



A Product Line of Diodes Incorporated



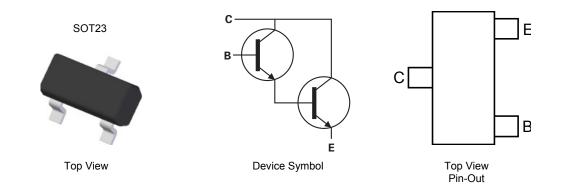
80V NPN DARLINGTON TRANSISTOR IN SOT23

Features

- BV_{CES} > 80V
- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- High Current Gain
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (€3)
- Weight 0.008 grams (approximate)



Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMBTA28-7-F	AEC-Q101	K6R	7	8	3,000
MMBTA28-13-F	AEC-Q101	K6R	13	8	10,000

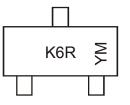
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K6R = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: B = 2014) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2010		2011	2012		2013	2014		2015	2016		2017
Code	Х		Y	Z		Α	В		С	D		E
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Νον	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D





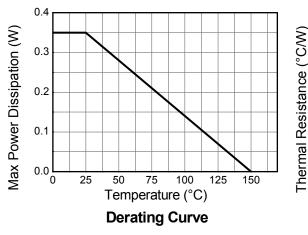
Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

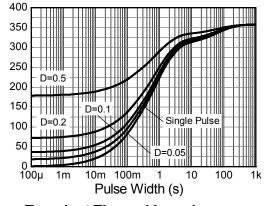
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	80	V
Collector-Emitter Voltage	V _{CES}	80	V
Emitter-Base Voltage	V _{EBO}	12	V
Continuous Collector Current	Ι _C	500	mA

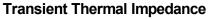
Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

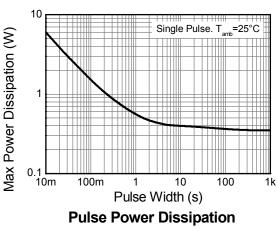
Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	D-	310	mW	
	(Note 6) PD		350	11100	
Thermal Desistance Junction to Ambient	(Note 5)	D	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	R _{θJA}	R _{0JA} 357		
Thermal Resistance, Junction to Leads	(Note 7)	R _{θJL}	350	°C/W	
Operating and Storage Temperature Range		T _J ,T _{STG}	-55 to +150	°C	

Notes: 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air b) For a device monitor of minimum recommended and out to copport that to conditions whilst operating in a steady-state.
c) Same as note (5), except the device is mounted on 15 mm x 15mm 1oz copper.
Thermal resistance from junction to solder-point (at the end of the leads).













Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

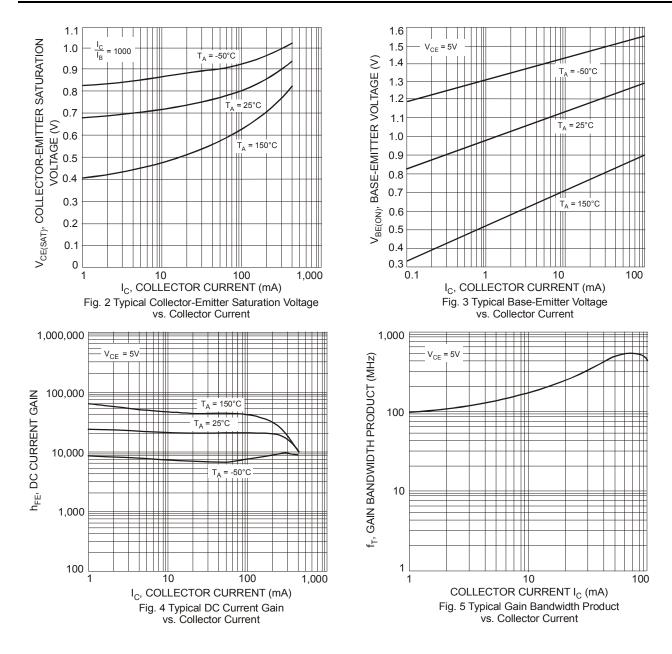
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Collector-Base Breakdown Voltage	BV _{CBO}	80	_	—	V	I _C = 100μA, I _E = 0	
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CES}	80	_	_	V	$I_{\rm C} = 100 \mu A, V_{\rm BE} = 0$	
Emitter-Base Breakdown Voltage	BV _{EBO}	12	_	—	V	$I_{\rm E} = 100 \mu A, I_{\rm C} = 0$	
Collector out off ourrent	I _{CBO}	_	_	100	nA	V _{CB} = 60V, I _E = 0	
Collector cut-off current	ICES	_	_	500	nA	V _{CE} = 60V, V _{BE} = 0	
Emitter-base Cut-off Current	I _{EBO}	_	_	100	nA	V _{EB} = 10V, I _C = 0	
ON CHARACTERISTICS (Note 8)							
Static Forward Current Transfer Ratio	h _{FE}	10,000 10,000	-	_	_	I _C = 10mA, V _{CE} = 5V I _C = 100mA, V _{CE} = 5V	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	_	1.2 1.5	V	I_{C} = 10mA, I_{B} = 10µA I_{C} = 100mA, I_{B} = 100µA	
Base-Emitter Turn-On Voltage	V _{BE(on)}	_	_	2.0	V	I _C = 100mA, V _{CE} = 5V	
SMALL SIGNAL CHARACTERISTICS (Note 8)							
Current Gain-Bandwidth Product	f _T	125	_	_	MHz	I _C = 10mA, V _{CE} = 5V, f = 100MHz	
Output Capacitance	C _{obo}	_	8.0	_	pF	V _{CB} = 10V, f = 1MHz, I _E = 0	
Input Capacitance	Cibo	_	15.0	_	pF	V _{EB} = 0.5V, f = 1MHz, I _C = 0	

8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2% Note:





Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

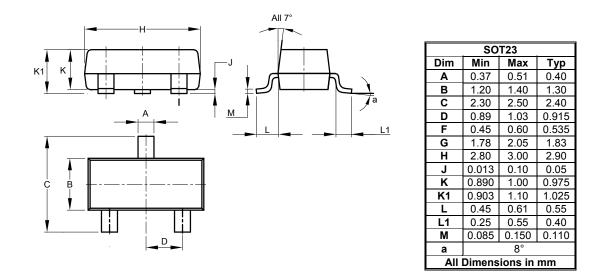






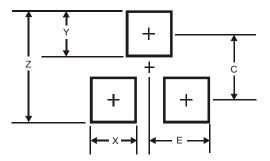
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35





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